

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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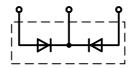




HiPerFRED™ Epitaxial Diode with common cathode and soft recovery

 $I_{FAV} = 2x15 A$ $V_{RRM} = 200 V$ $t_{rr} = 25 ns$

| V _{RSM} | V _{RRM} | Туре |
|------------------|------------------|--------------|
| 200 | 200 | DSEC 29-02AS |



TO-263



A = Anode, C = Cathode, TAB = Cathode

| Symbol | Conditions | Maximum | Maximum Ratings | |
|---|---|---------------------------|------------------------|--|
| I _{FRMS} | T _C = 150°C; rectangular, d = 0.5 | 35 15 | A A | |
| I _{FSM} | $T_{VJ} = 45$ °C; $t_p = 10$ ms (50 Hz), sine | 140 | A | |
| E _{AS} | $T_{VJ} = 25^{\circ}\text{C}$; non-repetitive $I_{AS} = 2.5 \text{ A}$; L = 180 μH | 0.8 | mJ | |
| I _{AR} | $V_A = 1.5 \cdot V_R \text{ typ.}; f = 10 \text{ kHz}; \text{ repetitive}$ | 0.3 | А | |
| T _{VJ} T _{VJM} T _{stg} | | -55+175 175 -55+150 | ე° ე° | |
| P _{tot} | T _C = 25°C | 95 | W | |
| M _d | mounting torque | 0.450.55 45 | Nm lb.in. | |
| Weight | typical | 2 | g | |

| Symbol | Conditions | Chara | acteristic | Values |
|-------------------------|---|-------|--------------|------------|
| | | typ. | max. | |
| I _R ① | $T_{VJ} = 25^{\circ}C; V_{R} = V_{RRM}$ $T_{VJ} = 150^{\circ}C; V_{R} = V_{RRM}$ | | 100 0.5 | μA mA |
| V _F 2 | $I_F = 15 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$ | | 0.86 1.06 | V V |
| R _{thJC} | | 0.5 | 1.6 | K/W K/W |
| t _{rr} | $I_F = 1 \text{ A}; -\text{di/dt} = 100 \text{ A/µs};$ $V_R = 30 \text{ V}; T_{VJ} = 25^{\circ}\text{C}$ | 25 | | ns |
| I _{RM} | $V_R = 100 \text{ V}; I_F = 25 \text{ A}; -di_F/dt = 100 \text{ A/}\mu\text{s}$ $T_{VJ} = 100^{\circ}\text{C}$ | 3.5 | 4.4 | Α |

Features

- International standard package
- Planar passivated chips
- · Very short recovery time
- Extremely low switching losses
- Low I_{RM}-values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- · Ultrasonic cleaners and welders

Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{RM} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

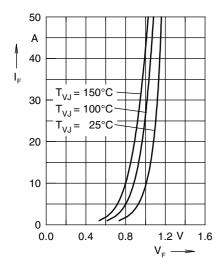
Dimensions see Outlines.pdf

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 % ② Pulse Width = 300 μ s, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

Recommended replacement: DPG 30C200PC







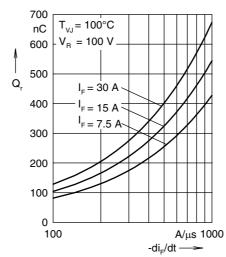


Fig. 2 Typ. reverse recovery charge Q,

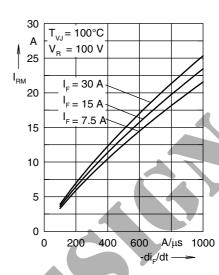


Fig. 3 Typ. peak reverse current I_{RM}

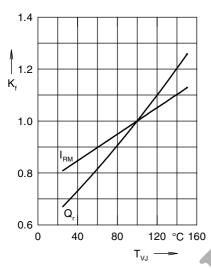


Fig. 4 Typ. dynamic parameters Q_r, I_{RM}

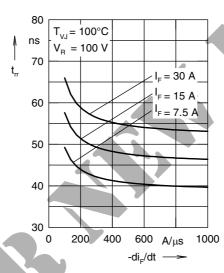


Fig. 5 Typ. recovery time t_{rr} versus -di_E/dt

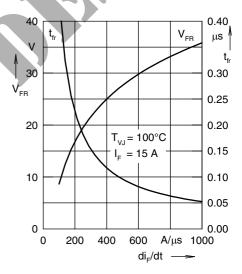


Fig. 6 Typ. peak forward voltage $V_{\rm FR}$ and $t_{\rm fr}$

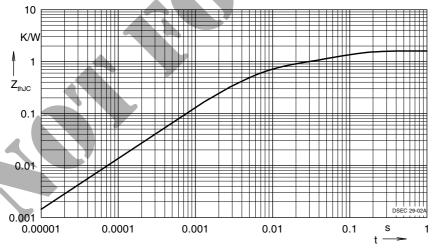


Fig. 7 Transient thermal resistance junction to case

Constants for Z_{th,IC} calculation:

| i | R _{thi} (K/W) | t _i (s) |
|---|------------------------|--------------------|
| 1 | 0.851 | 0.0052 |
| 2 | 0.328 | 0.0003 |
| 4 | 0.421 | 0.0409 |

IXYS reserves the right to change limits, test conditions and dimensions.